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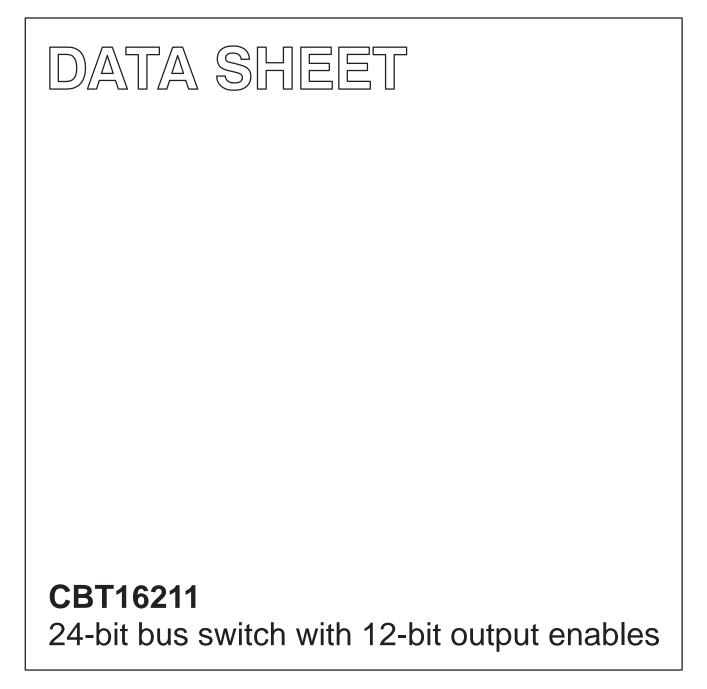
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Kind regards,

Team Nexperia

INTEGRATED CIRCUITS



Product data

2001 Jun 13



CBT16211

FEATURES

- 5 Ω switch connection between two ports
- TTL compatible control input levels
- Package options include plastic shrink small outline (SSOP), thin shrink small outline (TSSOP)
- ESD protection exceeds 1000 V CDM per JESD22-C101
- Latch-up testing is done to JESDEC Standard JESD78 which exceeds 100 mA

DESCRIPTION

The CBT16211 provides 24 bits of high-speed TTL-compatible bus switching. The low on-state resistance of the switch allows connections to be made with minimal propagation delay.

The device is organized as a dual 12-bit bus switch with separate output-enable (\overline{OE}) inputs. It can be used as two 12-bit bus switches or as one 24-bit bus switch. When \overline{OE} is low, the associated 12-bit bus switch is on, and port A is connected to port B. When \overline{OE} is high, the switch is open, and a high-impedance state exists between the ports.

The CBT16211 is characterized for operation from -40 to 85 °C.

QUICK REFERENCE DATA

| SYMBOL | PARAMETER | CONDITIONS T _{amb} = 25 °C; GND = 0 V | TYPICAL | UNIT |
|--------------------------------------|-------------------------------|---|---------|------|
| t _{PLH} t _{PHL} | Propagation delay An to Yn | C _L = 50 pF; V _{CC} = 5 V | 0.25 | ns |
| C _{IN} | Input capacitance | $V_I = 0 V \text{ or } V_{CC}$ | 4.3 | pF |
| C _{OUT} | Output capacitance | Outputs disabled; $V_O = 0 V \text{ or } V_{CC}$ | 6.9 | pF |
| Icc | Total supply current | Outputs disabled; V_{CC} = 5.5 V | 3.0 | μΑ |

ORDERING INFORMATION

| PACKAGES | TEMPERATURE RANGE | ORDER CODE | DWG NUMBER |
|------------------------------|-------------------|-------------|------------|
| 56-Pin Plastic SSOP Type III | –40 to 85 °C | CBT16211DL | SOT371-1 |
| 56-Pin Plastic TSSOP Type II | –40 to 85 °C | CBT16211DGG | SOT364-1 |

FUNCTION TABLE

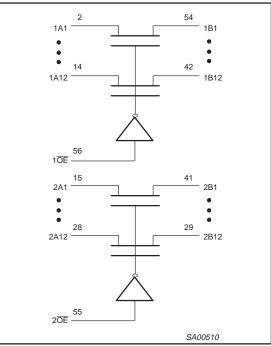
| INP | JTS | OUTPUTS | | |
|-----|-------------------|---------|---------|--|
| 10E | 2 <mark>0E</mark> | 1A, 1B | 2A, 2B | |
| L | L | 1A = 1B | 2A = 2B | |
| L | Н | 1A = 1B | Z | |
| н | L | Z | 2A = 2B | |
| н | Н | Z | Z | |

H = High voltage level

L = Low voltage level

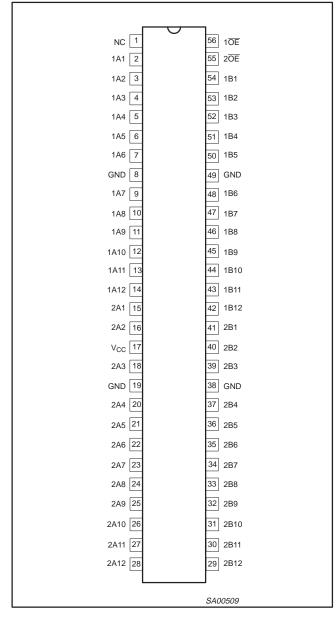
Z = High impedance "off" state

LOGIC SYMBOL



CBT16211

PIN CONFIGURATION



PIN DESCRIPTION

| PIN NUMBER | SYMBOL | NAME AND FUNCTION |
|---|--------------------------|-------------------------|
| 1 | NC | No internal connection |
| 56, 55 | 1 <u>0E,</u> 2 <u>0E</u> | Output Enables |
| 2, 3, 4, 5, 6, 7, 9, 10, 11, 12, 13, 14 | 1A1-1A12 | Inputs |
| 54, 53, 52, 51, 50, 48, 47, 46, 45, 44, 43, 42 | 1B1-1B12 | Outputs |
| 15, 16, 18, 20, 21, 22, 23, 24, 25, 26, 27, 28 | 2A1-2A12 | Inputs |
| 41, 40, 39, 37, 36, 35, 34, 33, 32, 31, 30, 29 | 2B1-2B12 | Outputs |
| 8, 19, 38, 49 | GND | Ground (0 V) |
| 17 | V _{CC} | Positive supply voltage |

CBT16211

ABSOLUTE MAXIMUM RATINGS^{1, 2}

| SYMBOL | PARAMETER | CONDITIONS | RATING | UNIT |
|------------------|--------------------------------|-----------------------------|--------------|------|
| V _{CC} | DC supply voltage | | –0.5 to +7.0 | V |
| I _{IK} | DC input diode current | V ₁ < 0 | -50 | mA |
| VI | DC input voltage ³ | | –0.5 to +7.0 | V |
| V _{OUT} | DC output voltage ³ | output in Off or High state | –0.5 to +5.5 | V |
| I _{OUT} | DC output current | output in Low state | 128 | mA |
| T _{stg} | Storage temperature range | | –65 to 150 | °C |

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

absolute-maximum-rated conditions for extended periods may affect device reliability.
The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150 °C.
The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

| SYMBOL PARAMETER | DADAMETED | LIM | UNIT | |
|------------------|--------------------------------------|-----|------|------|
| | PARAMETER | Min | Max | UNIT |
| V _{CC} | DC supply voltage | 4.5 | 5.5 | V |
| V _{IH} | High-level input voltage | 2.0 | — | V |
| V _{IL} | Low-level Input voltage | — | 0.8 | V |
| T _{amb} | Operating free-air temperature range | -40 | +85 | °C |

DC ELECTRICAL CHARACTERISTICS

| | | | | LIMITS | | |
|------------------------------|--|--|----------------------------------|------------------|------|----|
| SYMBOL | PARAMETER | TEST CONDITIONS | T _{amb} = −40 to +85 °C | | | |
| | | | Min | Typ ¹ | Max | 1 |
| V _{IK} | Input clamp voltage | $V_{CC} = 4.5 \text{ V}; I_{I} = -18 \text{ mA}$ | - | — | -1.2 | V |
| VP | Output high pass voltage | $V_{IN} = V_{CC} = 5.0 \text{ V}; I_{OUT} = -100 \mu\text{A}$ | 3.4 | 3.6 | 3.9 | V |
| | Input lookago ourrept | $V_{CC} = 0 V; V_{I} = 5.5 V$ | — | — | 10 | |
| l II | Input leakage current | V_{CC} = 5.5 V; V_{I} = GND or 5.5 V | — | — | ±1 | μA |
| I _{CC} | Quiescent supply current | $V_{CC} = 5.5 \text{ V}; I_O = 0, V_I = V_{CC} \text{ or GND}$ | — | — | 3 | μΑ |
| ΔI _{CC} | Additional supply current per input pin ² | V_{CC} = 5.5 V, one input at 3.4 V, other inputs at V_{CC} or GND | - | — | 2.5 | mA |
| CI | Control pins | V _I = 3 V or 0 | — | 4.5 | — | pF |
| C _{I(OFF)} | Port OFF capacitance | $V_{O} = 3 V \text{ or } 0, \overline{OE} = V_{CC}$ | — | 6.9 | — | pF |
| | | $V_{CC} = 4.0 \text{ V}; V_1 = 2.4 \text{ V}; I_1 = 15 \text{ mA}$ | — | 14 | 20 | |
| - 3 | | $V_{CC} = 4.5 \text{ V}; V_1 = 0 \text{ V}; I_1 = 64 \text{ mA}$ | — | 5 | 7 | Ω |
| r _{on} ³ | | $V_{CC} = 4.5 \text{ V}; \text{ V}_1 = 0 \text{ V}; \text{ I}_1 = 30 \text{ mA}$ | — | 5 | 7 | |
| | | $V_{CC} = 4.5 \text{ V}; V_1 = 2.4 \text{ V}; I_1 = -15 \text{ mA}$ | | 8 | 12 | |

NOTES:

1. All typical values are at V_{CC} = 5 V, T_{amb} = 25 °C.

2. This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.

3. Measured by the voltage drop between the A and the B terminals at the indicated current through the switch.

On-state resistance is determined by the lowest voltage of the two (A or B) terminals.

CBT16211

AC CHARACTERISTICS

 $GND = 0 V; t_{R}; C_{L} = 50 pF$

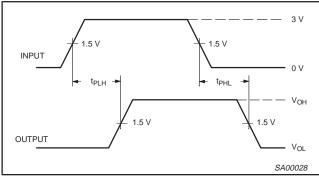
| SYMBOL | PARAMETER | FROM TO (INPUT) (OUTPUT) | то | V_{CC} = 5.0 V ± 0.5 V | | UNIT |
|------------------|--|-----------------------------|--------|------------------------------|------|------|
| STWBOL | PARAMETER | | Min | Мах | | |
| t _{pd} | Propagation delay ¹ | A or B | B or A | — | 0.25 | ns |
| t _{en} | Output enable time to High and Low level | ŌĒ | A or B | 1.5 | 6.0 | ns |
| t _{dis} | Output disable time from High and Low level | ŌE | A or B | 1.5 | 6.0 | ns |

NOTE:

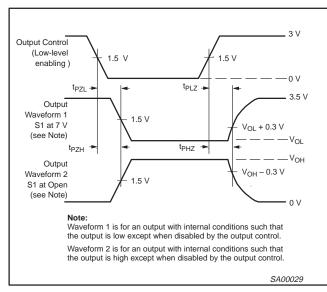
1. This parameter is warranted but not production tested. The propagation delay is based on the RC time constant of the typical on-state resistance of the switch and a load capacitance of 50 pF, when driven by an ideal voltage source (zero output impedance).

AC WAVEFORMS

 V_{M} = 1.5 V, V_{IN} = GND to 3.0 V.

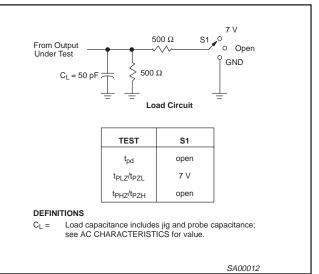


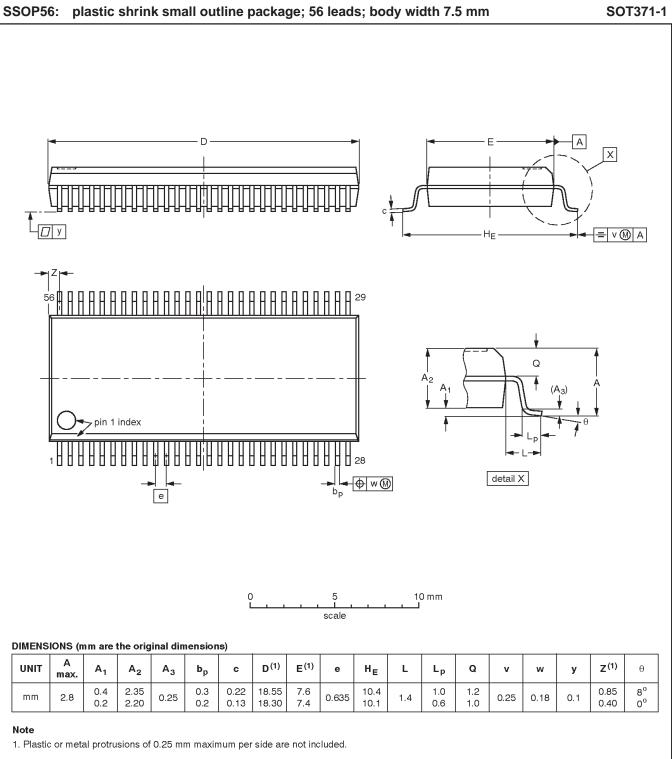
Waveform 1. Input (An) to Output (Yn) Propagation Delays



Waveform 2. 3-State Output Enable and Disable Times

TEST CIRCUIT AND WAVEFORMS

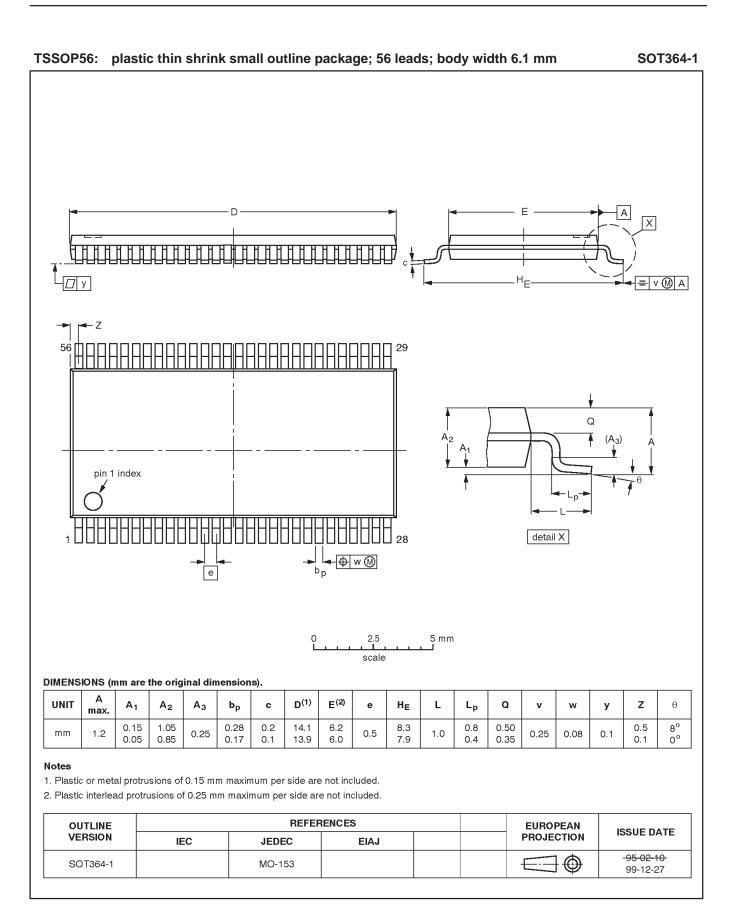




| OUTLINE | JTLINE REFERENCES | | EUROPEAN | ISSUE DATE | | |
|----------|-------------------|--------|----------|------------|------------|----------------------------------|
| VERSION | IEC | JEDEC | EIAJ | | PROJECTION | |
| SOT371-1 | | MO-118 | | | | -95-02-04 99-12-27 |

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CBT16211



Product data

CBT16211

Data sheet status

| Data sheet status ^[1] | Product status ^[2] | Definitions |
|----------------------------------|----------------------------------|--|
| Objective data | Development | This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice. |
| Preliminary data | Qualification | This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product. |
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[1] Please consult the most recently issued datasheet before initiating or completing a design.

[2] The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.

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